

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

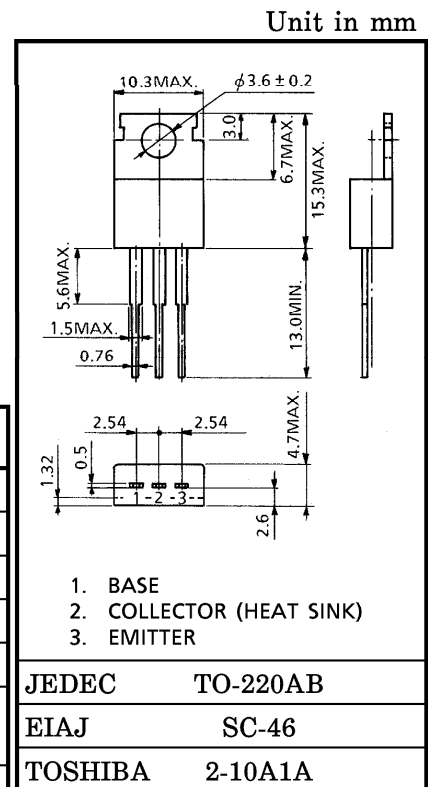
2SD526

POWER AMPLIFIER APPLICATIONS

- High Power Dissipation : $P_C = 30\text{W}$ ($T_c = 25^\circ\text{C}$)
- Good Linearity of h_{FE} .
- Complementary to 2SB596.
- Recommend for 20~25W High Fidelity Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	4	A
Base Current	I_B	0.4	A
Collector Power Dissipation ($T_c = 25^\circ\text{C}$)	P_C	30	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55 \sim 150$	$^\circ\text{C}$



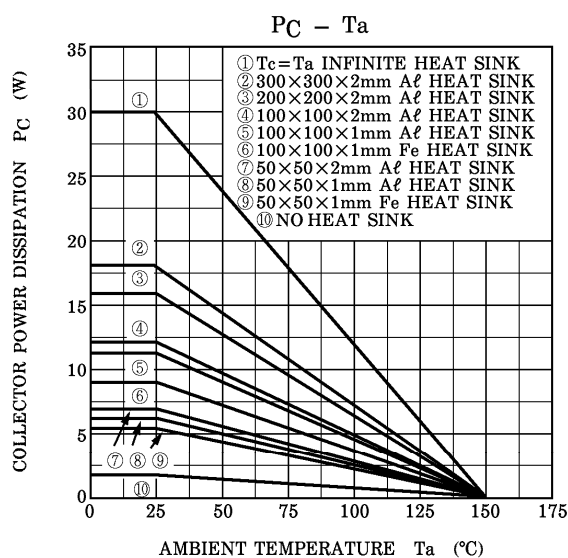
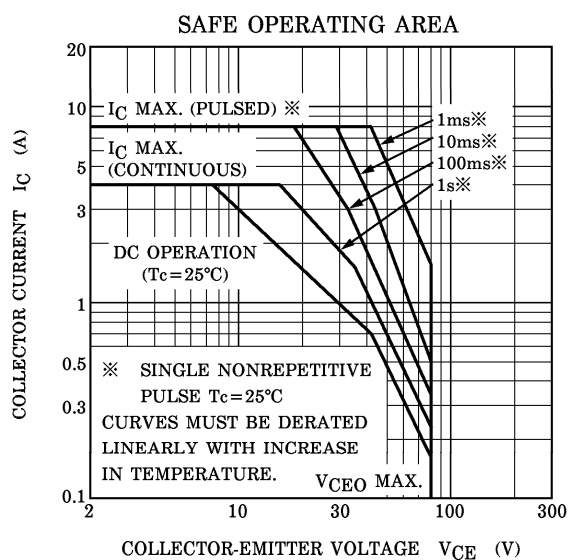
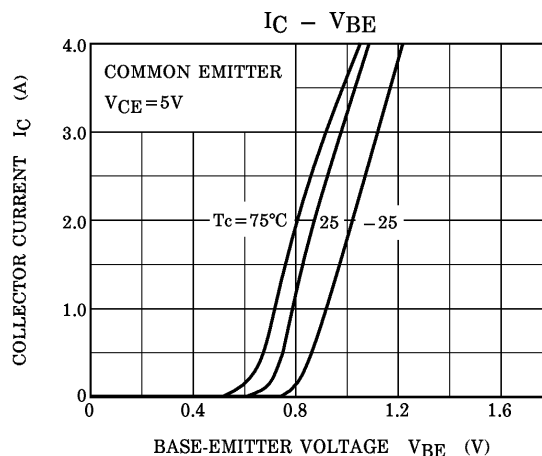
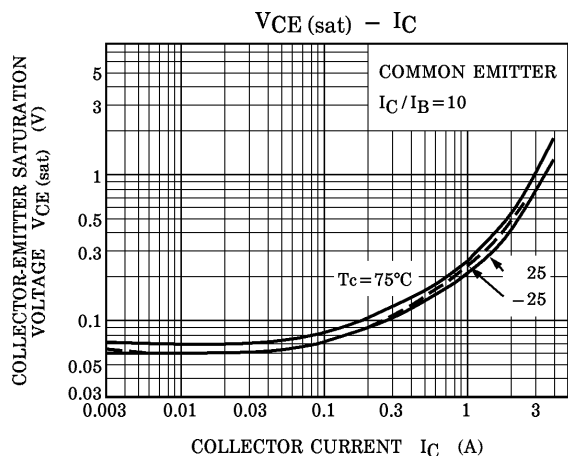
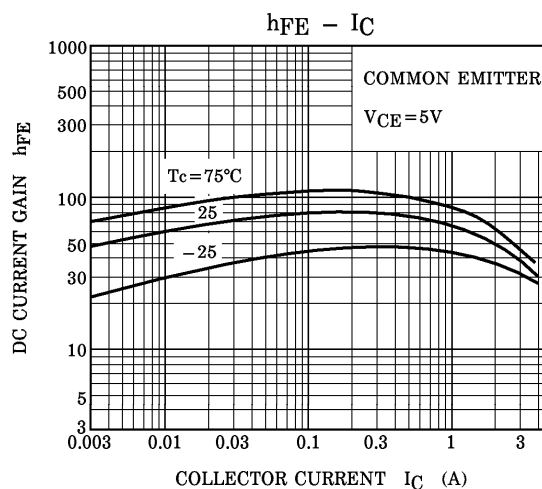
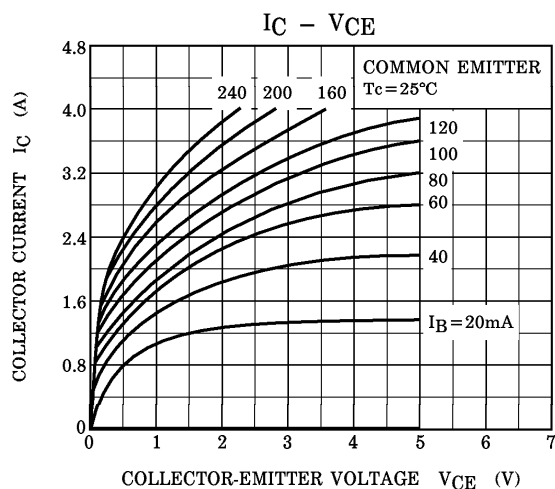
Weight : 1.9g

Mounting Kit No. AC75

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 80\text{V}$, $I_E = 0$	—	—	30	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 5\text{V}$, $I_C = 0$	—	—	100	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 50\text{mA}$, $I_B = 0$	80	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE} = 5\text{V}$, $I_C = 0.5\text{A}$	40	—	240	
	$h_{FE(2)}$	$V_{CE} = 5\text{V}$, $I_C = 3\text{A}$	15	50	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 3\text{A}$, $I_B = 0.3\text{A}$	—	0.45	1.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = 5\text{V}$, $I_C = 3\text{A}$	—	1.0	1.5	V
Transition Frequency	f_T	$V_{CE} = 5\text{V}$, $I_C = 0.5\text{A}$	3	8	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$	—	90	—	pF

Note : $h_{FE(1)}$ Classification R : 40~80, O : 70~140, Y : 120~240



RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.